

Description

The XPX60N04RX uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

Battery protoction of in other Cwitching application

General Features

 $V_{DS} = 40V I_{D} = 60 A$

 $R_{DS(ON)}$ < 15.5m Ω @ V_{GS} =10V

Application

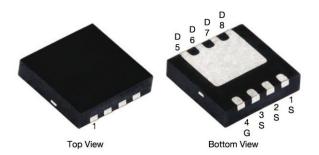
Battery protection

Load switch

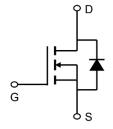
Uninterruptible power supply

ROHS

Pin Configurations



TDFN3.3*3.3-8L/TDFN3*3-8L



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
XPX60N04RX	PDFN3*3-8L	XPX60N04RX XXX YYYY	5000

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	40	V
Vgs	Gate-Source Voltage	±20	V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	60	А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	26	А
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	10	А
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	8	А
Ідм	Pulsed Drain Current ²	100	А
EAS	Single Pulse Avalanche Energy ³	31	mJ
las	Avalanche Current	25	Α
P _D @T _C =25°C	Total Power Dissipation ⁴	34.7	W
P _D @T _A =25°C	Total Power Dissipation⁴	2	W
Тѕтс	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
R₀JA	Thermal Resistance Junction-ambient (Steady State)¹	62	°C/W
Rejc	Thermal Resistance Junction-Case ¹	3.6	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	40			V
2BV DSS/ 2T J	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA		0.034		V/°C
		V _{GS} =10V , I _D =20A		12.5	15.5	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =10A		14.5	20	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}$, $I_D=250uA$	1.0	1.5	2.5	V
$\mathbb{P}V_{GS(th)}$	V _{GS(th)} Temperature Coefficient			-5.64		mV/°C
		V _{DS} =32V , V _{GS} =0V , T _J =25°C			1	
IDSS	Drain-Source Leakage Current	V _{DS} =32V , V _{GS} =0V , T _J =55°C			5	uA
lgss	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =20A		36		S
R _g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		2.1	4.2	Ω
Qg	Total Gate Charge (4.5V)			10.7		
Qgs	Gate-Source Charge	V _{DS} =20V , V _{GS} =4.5V , I _D =12A		3.3		nC
Qgd	Gate-Drain Charge			4.2		
Td(on)	Turn-On Delay Time			8.6		
Tr	Rise Time	V _{DD} =12V , V _{GS} =10V ,		3.4		
Td(off)	Turn-Off Delay Time	—R _G =3.3 I _D =6A		25		ns
T _f	Fall Time			2.2		
Ciss	Input Capacitance			1314		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		120		pF
Crss	Reverse Transfer Capacitance	_		88		
ls	Continuous Source Current ^{1,5}				42	Α
Ism	Pulsed Source Current ^{2,5}	V _G =V _D =0V , Force Current			100	Α
Vsp	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1.2	V

Note

^{1.}The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

^{2.}The data tested by pulsed , pulse width $\leqq 300 \text{us}$, duty cycle $\leqq 2\%$

^{3.}The EAS data shows Max. rating . The test condition is V_{DD} =25V, V_{GS} =10V,L=0.1mH, I_{AS} =25A

^{4.} The power dissipation is limited by 150°C junction temperature

^{5 .}The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.



Typical Characteristics

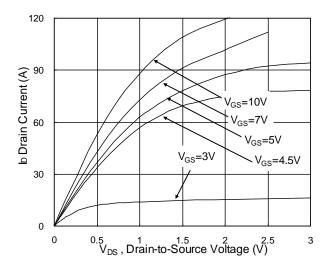


Fig.1 Typical Output Characteristics

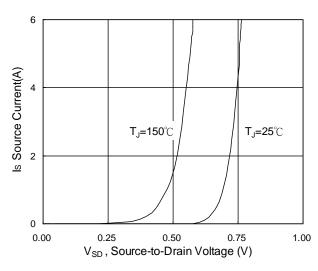


Fig.3 Forward Characteristics of Reverse

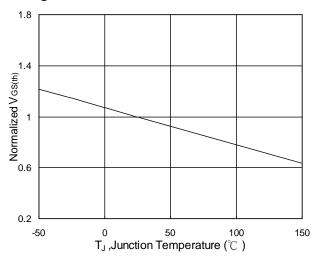


Fig.5 V_{GS(th)} vs. T_J

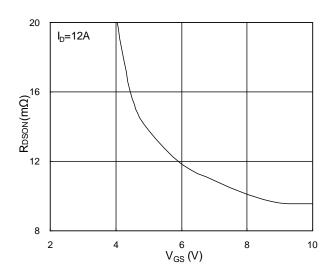


Fig.2 On-Resistance vs. G-S Voltage

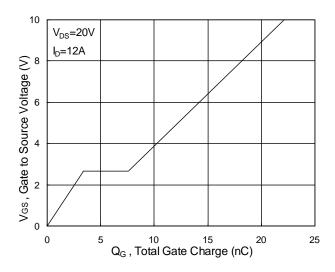


Fig.4 Gate-Charge Characteristics

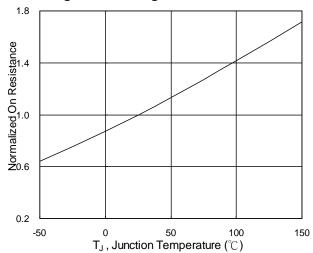
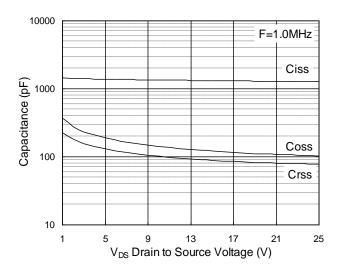


Fig.6 Normalized R_{DSON} vs. T_J





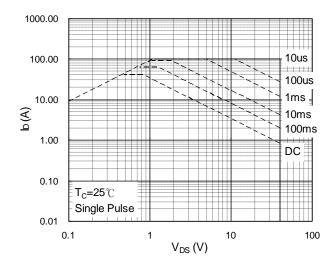


Fig.7 Capacitance

Fig.8 Safe Operating Area

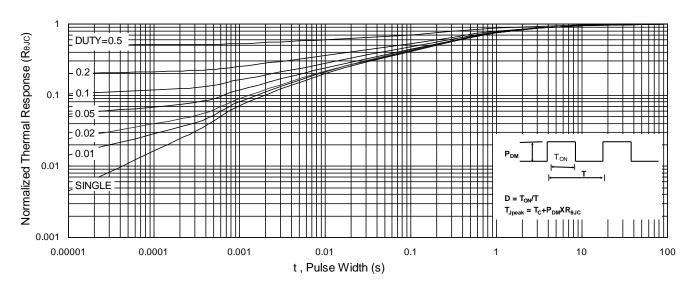


Fig.9 Normalized Maximum Transient Thermal Impedance

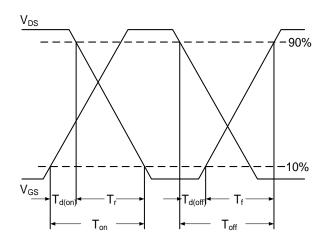


Fig.10 Switching Time Waveform

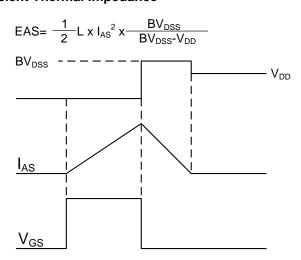
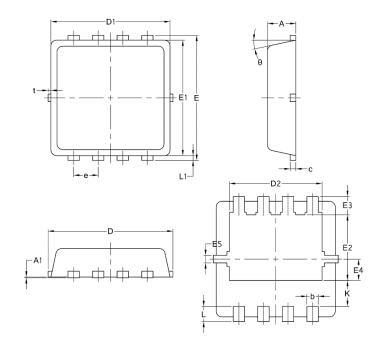


Fig.11 Unclamped Inductive Switching Waveform



Package Mechanical Data-DFN3*3-8L-JQ Single



	Common mm			
Symbol				
	Mim	Nom	Max	
Α	0.70	0.75	0.85	
A1	/	/	0.05	
b	0.20	0.30	0.40	
С	0.10	0.152	0.25	
D	3.15	3.30	3.45	
D1	3.00	3.15	3.25	
D2	2.29	2.45	2.65	
E	3.15	3.30	3.45	
E1	2.90	3.05	3.20	
E2	1.54	1.74	1.94	
E3	0.28	0.48	0.65	
E4	0.37	0.57	0.77	
E5	0.10	0.20	0.30	
е	0.60	0.65	0.70	
K	0.59	0.69	0.89	
L	0.30	0.40	0.50	
L1	0.06	0.125	0.20	
t	0	0.075	0.13	
Ф	10	12	14	



Flow (wave) soldering (solder dipping)

Product	Peak Temperature	Dipping Time
Pb device	245 ℃ ±5 ℃	5sec±1sec
Pb-Free device	260℃+0/-5℃	5sec±1sec



This integrated circuit can be damaged by ESD UniverChip Corporation recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedure can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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